# 2SC513

Silicon NPN Triple Diffused Planar Transistor (High Voltage and High Speed Switching Transistor)

**Application:** Switching Regulator and General Purpose

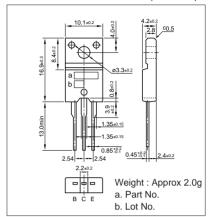
■Absolute maximum ratings (Ta=25°C)

Symbol	Ratings	Unit
Vсво	600	V
VCEO	400	V
VEBO	10	V
Ic	5(Pulse10)	А
Ів	2	А
Pc	30(Tc=25°C)	W
Tj	150	°C
Tstg	-55 to +150	°C

## **■**Electrical Characteristics

■Electrical Cl	naracteristics	(Ta=25°C)			
Symbol	Conditions	Ratings	Unit		
Ісво	Vcb=500V	100max	μΑ		
ГЕВО	Veb=10V	10max	μΑ		
V(BR)CEO	Ic=25mA	400min	V		
hfe	Vce=4V, Ic=1.5A	10 to 30			
Vce(sat)	Ic=1.5A, IB=0.3A	0.5max	V		
VBE(sat)	Ic=1.5A, IB=0.3A	1.3max	V		
fт	Vce=12V, Ie=-0.3A	20typ	MHz		
Сов	VcB=10V, f=1MHz	30typ	pF		

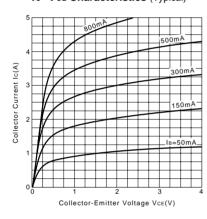
# External Dimensions FM20(TO220F)



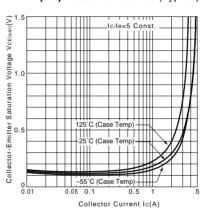
# ■Typical Switching Characteristics (Common Emitter)

Vcc (V)	R <sub>L</sub> (Ω)	Ic (A)	V <sub>BB1</sub> (V)	V <sub>BB2</sub> (V)	I <sub>B1</sub> (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
200	133	1.5	10	-5	0.15	-0.3	1max	2max	0.3max

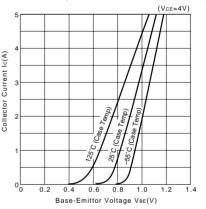
## Ic-VcE Characteristics (Typical)



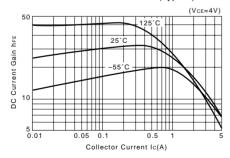
VcE(sat)-Ic Characteristics (Typical)



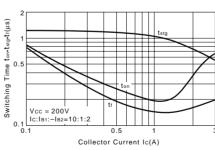
Ic-VBE Temperature Characteristics (Typical)



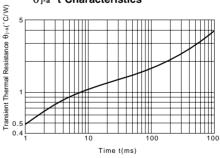
hfe-Ic Characteristics (Typical)



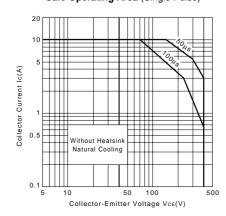
ton • tstg • tf-Ic Characteristics (Typical)



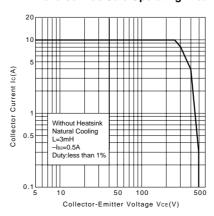
 $\theta_{j-a}$ -t Characteristics



Safe Operating Area (Single Pulse)



**Reverse Bias Safe Operating Area** 



Pc-Ta Derating

